

Part Number = 3SK80

Description = N-Channel, Dual-Gate Tetrode MOSFET

Manufacturer = Hitachi Semiconductor

V(BR)DSS (V) = 20

V(BR)GSS (V) = 8

I(D) Abs. Drain Current (A) = 50m

Absolute Max. Power Diss. (W) = 200m

@(VDS) (V) (Test Condition) = 8

I(DSS) Min. (A) = 20m

I(GSS) Max. (A) = 20n

g(fs) Min. (S) Trans. conduct. = 7m

@V(DS) (V) (Test Condition) = 15

C(iss) Max. (F) = 5p

Package = Macro-X